

YJ Planar Schottky Barrier Diode Die Specification

100V 3A, 55mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB055H100SS-280A

Main Products Characteristics

- Average forward current $I_{F(AV)}$ at $V_F = 1.0V$, $I_{RMS} = 3.0A$, $f = 100Hz$, $T_J = 100^\circ C$